

DATA SHEET

BF861A; BF861B; BF861C N-channel junction FETs

Product specification
Supersedes data of 1995 Apr 14
File under Discrete Semiconductors, SC07

1997 Sep 04

N-channel junction FETs

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FEATURES

- High transfer admittance
- Low input capacitance
- Low feedback capacitance
- Low noise.

APPLICATIONS

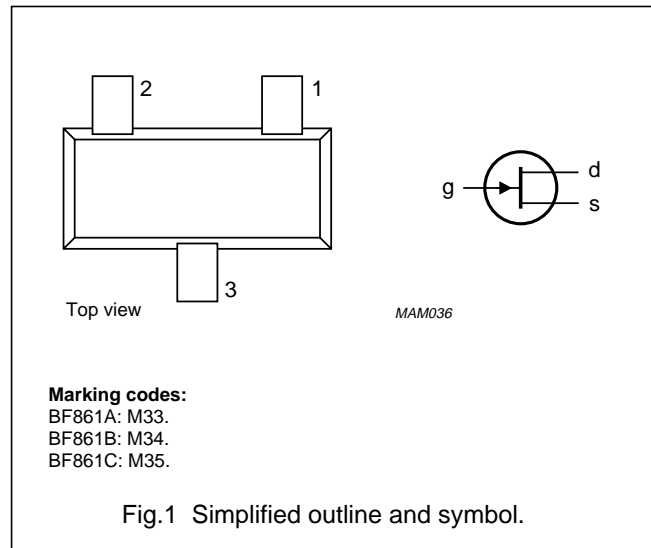
- Preamplifiers for AM tuners in car radios.

DESCRIPTION

N-channel symmetrical junction field effect transistors in a SOT23 package.

PINNING - SOT23

PIN	SYMBOL	DESCRIPTION
1	s	source
2	d	drain
3	g	gate



CAUTION

The device is supplied in an antistatic package. The gate-source input must be protected against static discharge during transport or handling.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DS}	drain-source voltage (DC)		–	25	V
I_{DSS}	drain current BF861A BF861B BF861C	$V_{GS} = 0; V_{DS} = 8 V$	2 6 12	6.5 15 25	mA mA mA
P_{tot}	total power dissipation	up to $T_{amb} = 25\text{ }^{\circ}\text{C}$	–	250	mW
$ y_{fs} $	forward transfer admittance BF861A BF861B BF861C	$V_{GS} = 0; V_{DS} = 8 V$	12 16 20	20 25 30	mS mS mS
C_{iss}	input capacitance	$f = 1\text{ MHz}$	–	10	pF
C_{rss}	reverse transfer capacitance	$f = 1\text{ MHz}$	–	2.7	pF

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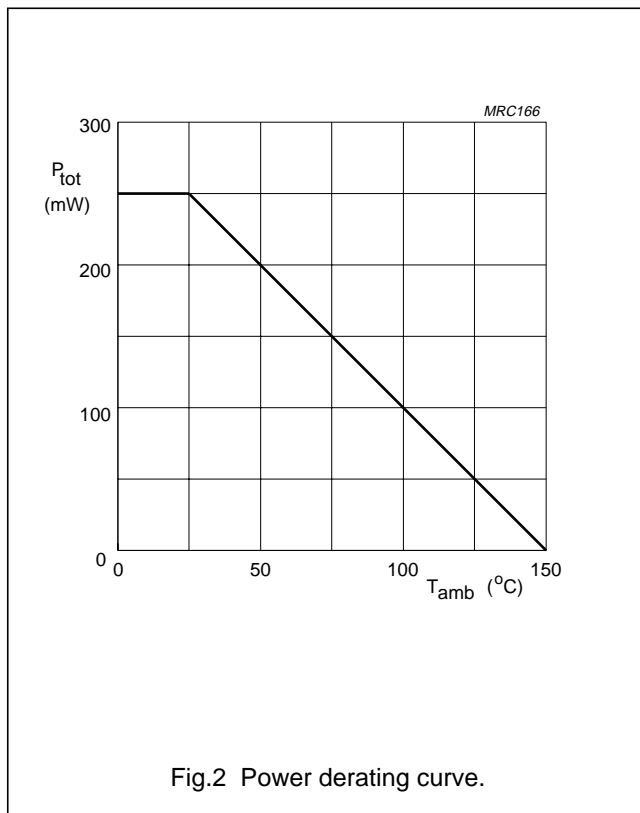
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DS}	drain-source voltage (DC)		–	25	V
V_{GSO}	gate-source voltage	open drain	–	25	V
V_{DGO}	drain-gate voltage (DC)	open source	–	25	V
I_G	forward gate current (DC)		–	10	mA
P_{tot}	total power dissipation	up to $T_{amb} = 25\text{ °C}$; note 1	–	250	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	operating junction temperature		–	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.



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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient; note 1	500	K/W

Note

1. Device mounted on an FR4 printed-circuit board.

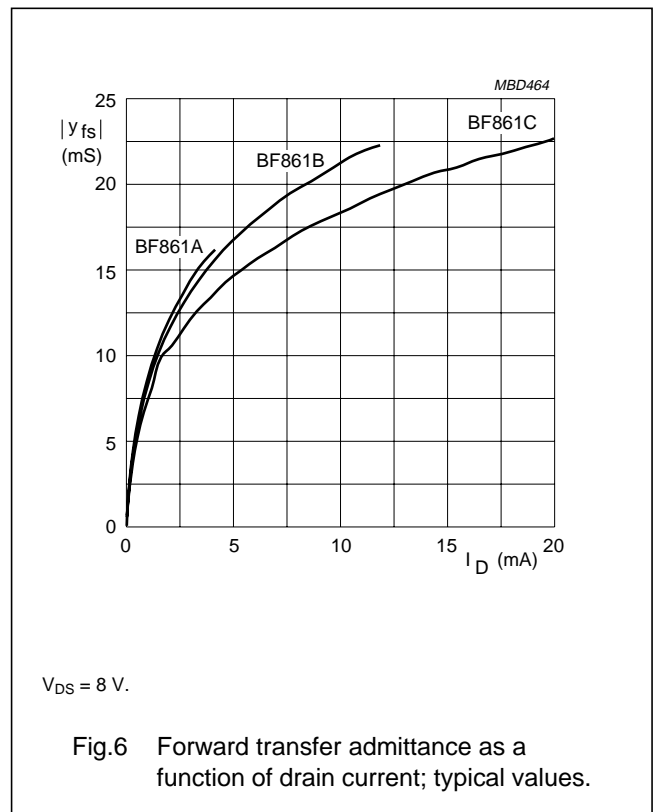
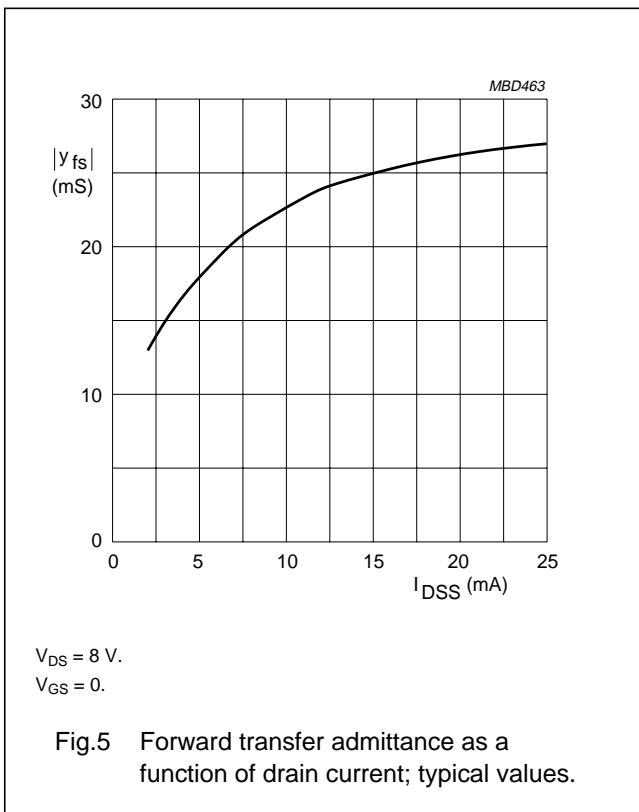
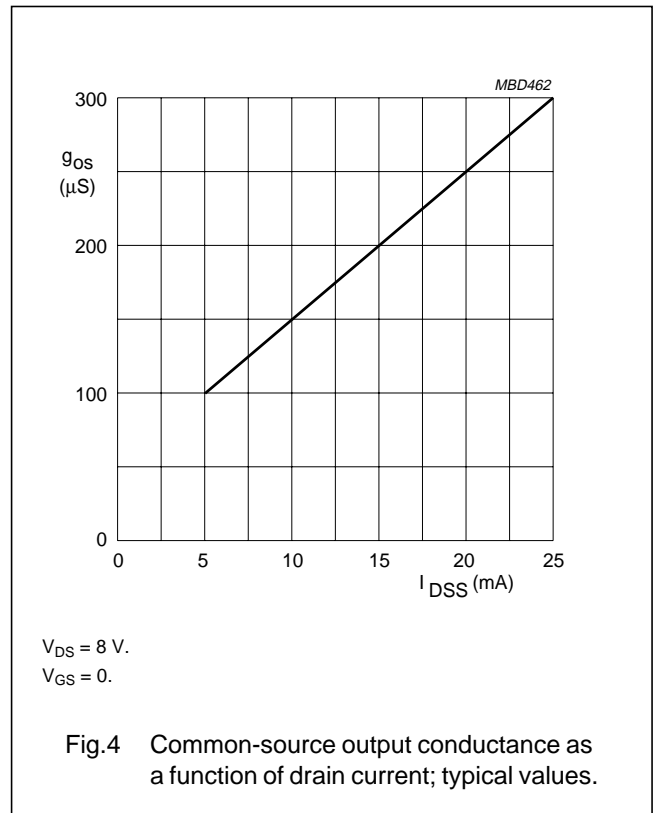
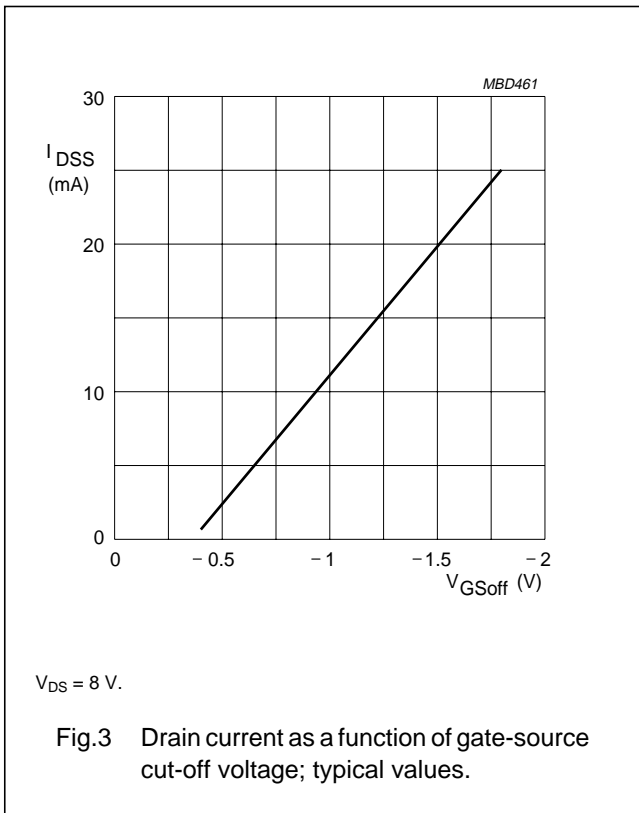
CHARACTERISTICS

$T_j = 25\text{ °C}$; $V_{DS} = 8\text{ V}$; $V_{GS} = 0$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)GSS}$	gate-source breakdown voltage	$I_G = -1\ \mu\text{A}$	-25	-	-	V
V_{GSoff}	gate-source cut-off voltage	$I_D = 1\ \mu\text{A}$				
	BF861A		-0.2	-	-1	V
	BF861B		-0.5	-	-1.5	V
	BF861C		-0.8	-	-2	V
V_{GSS}	gate-source forward voltage	$V_{DS} = 0$; $I_G = 1\ \text{mA}$	-	-	1	V
I_{DSS}	drain current					
	BF861A		2	-	6.5	mA
	BF861B		6	-	15	mA
	BF861C		12	-	25	mA
I_{GSS}	gate cut-off current	$V_{GS} = -20\ \text{V}$; $V_{DS} = 0$	-	-	-1	nA
$ y_{fs} $	forward transfer admittance					
	BF861A		12	-	20	mS
	BF861B		16	-	25	mS
	BF861C		20	-	30	mS
g_{os}	common source output conductance					
	BF861A		-	-	200	μS
	BF861B		-	-	250	μS
	BF861C		-	-	300	μS
C_{iss}	input capacitance	$f = 1\ \text{MHz}$	-	-	10	pF
C_{rss}	reverse transfer capacitance	$f = 1\ \text{MHz}$	-	2.1	2.7	pF
V_n/\sqrt{B}	equivalent input noise voltage	$V_{GS} = 0$; $f = 1\ \text{MHz}$	-	1.5	-	$\text{nV}/\sqrt{\text{Hz}}$

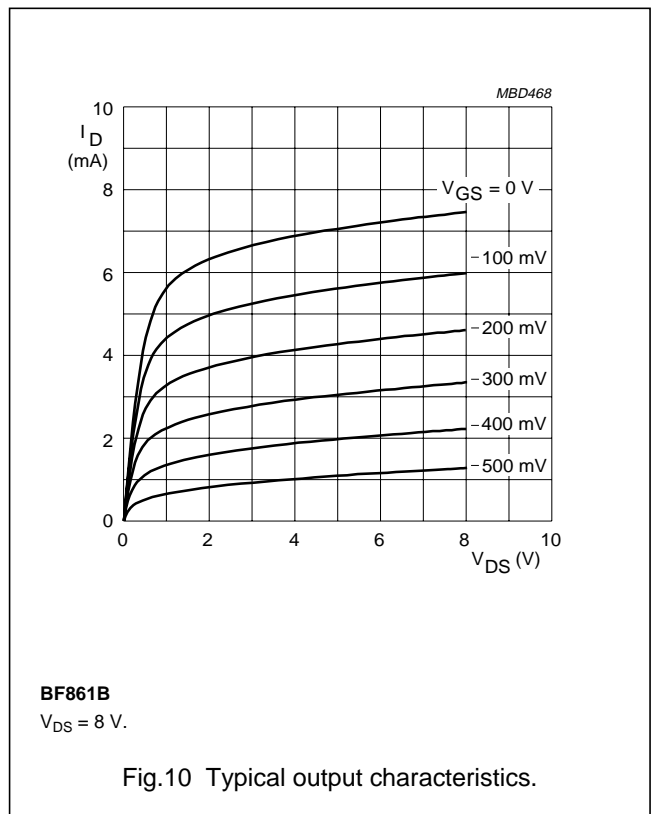
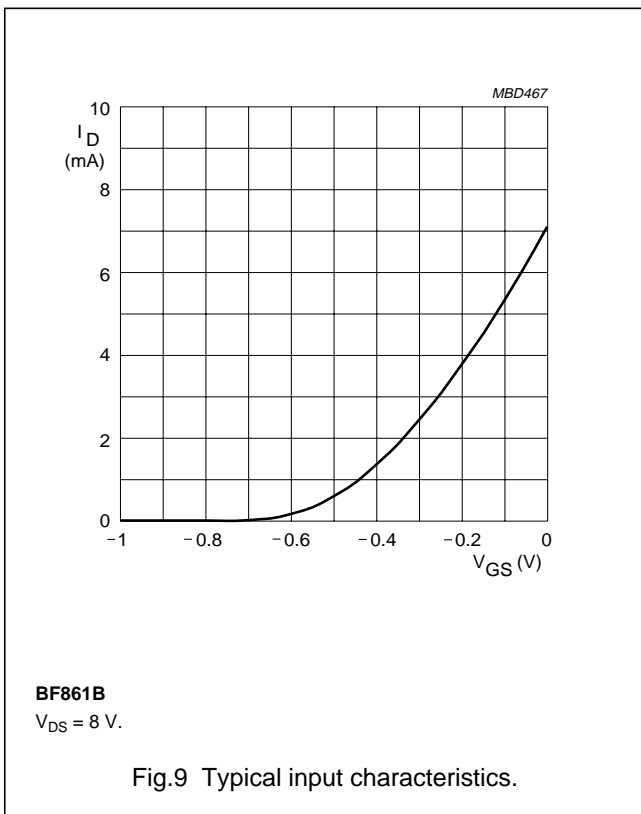
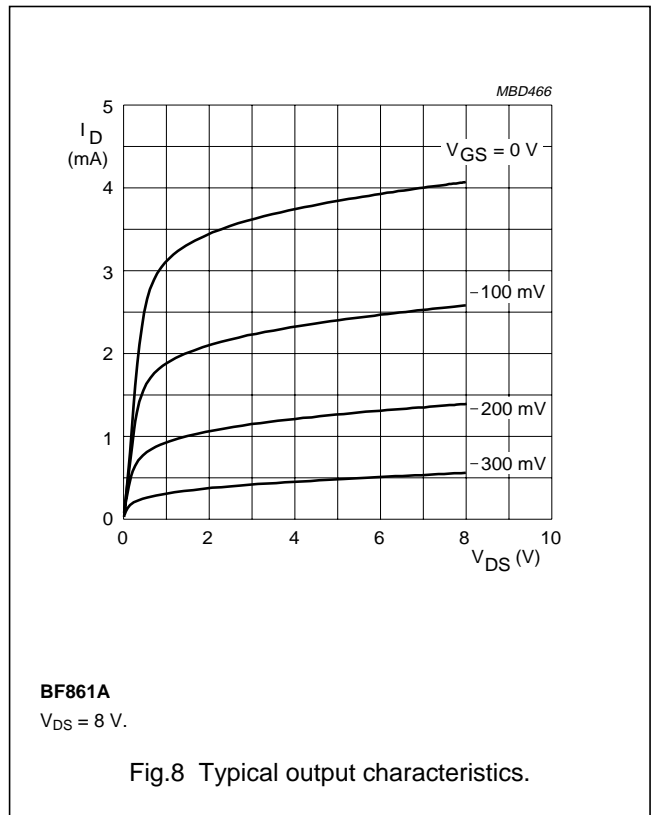
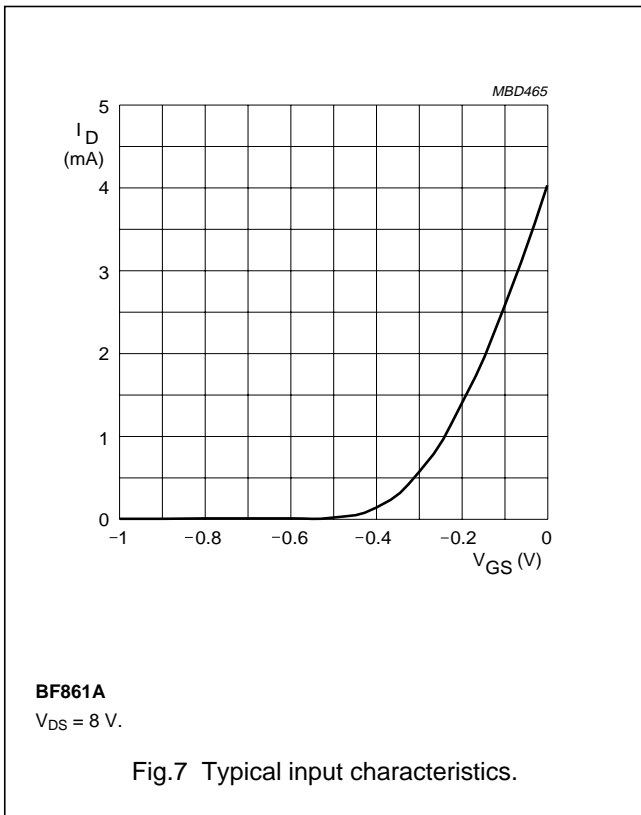
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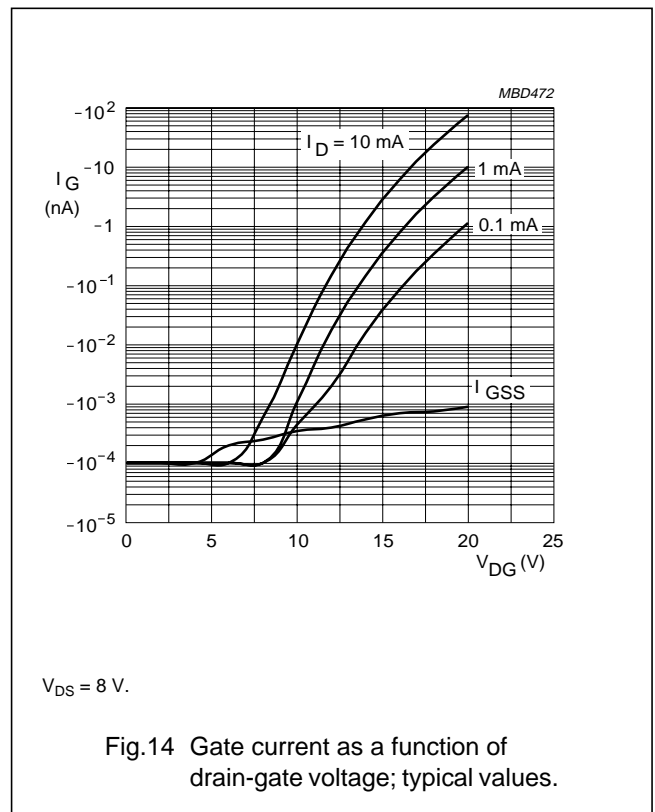
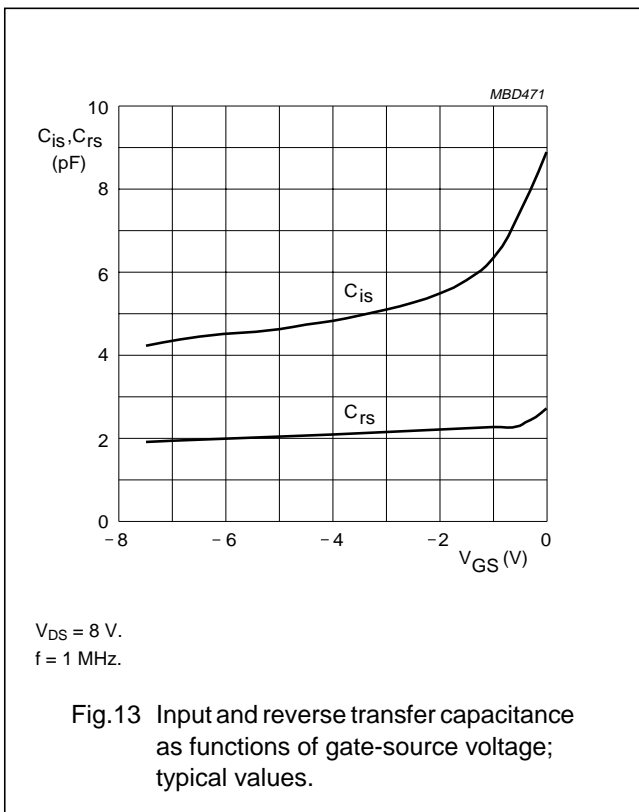
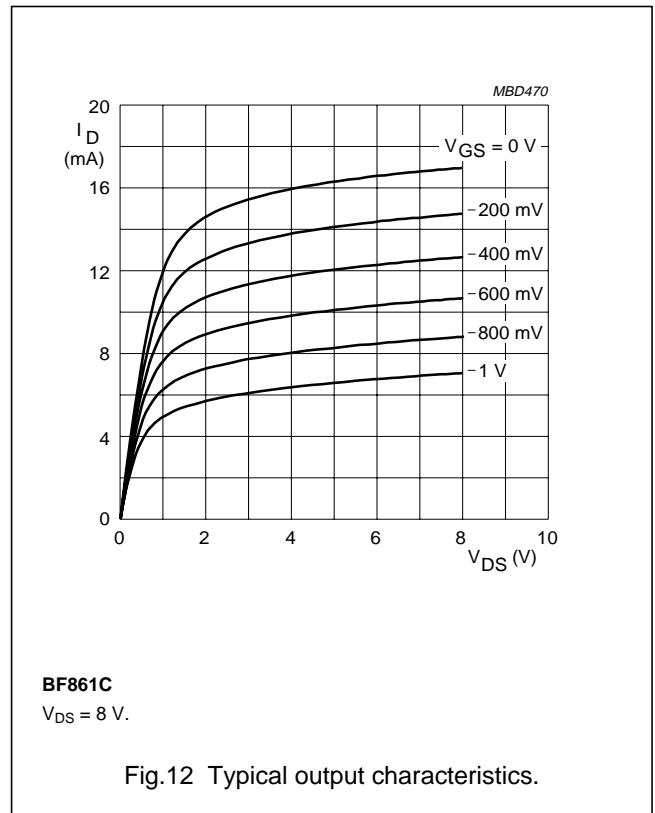
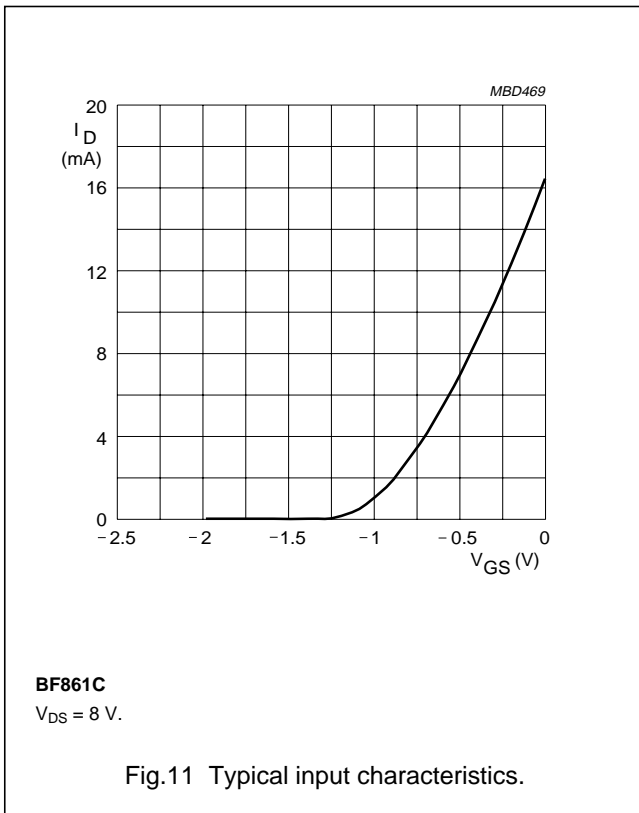
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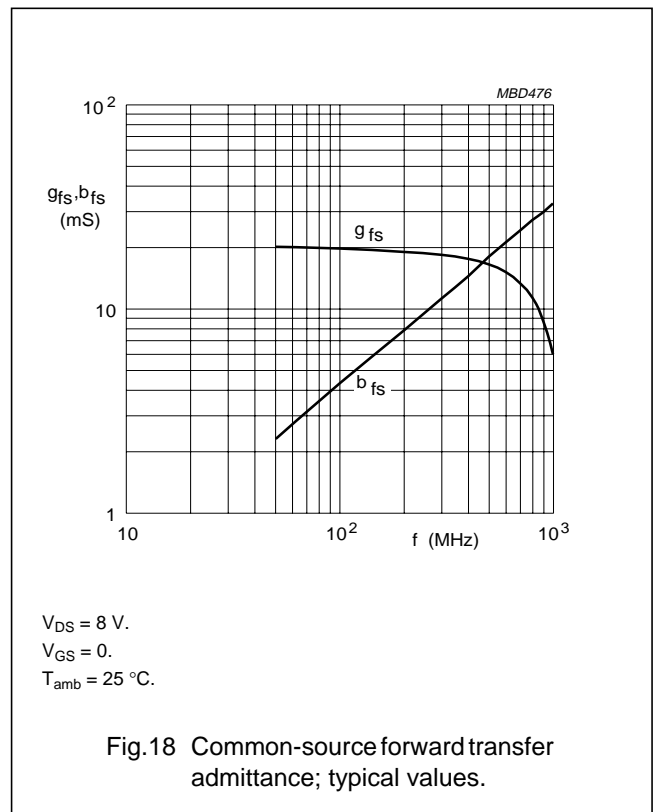
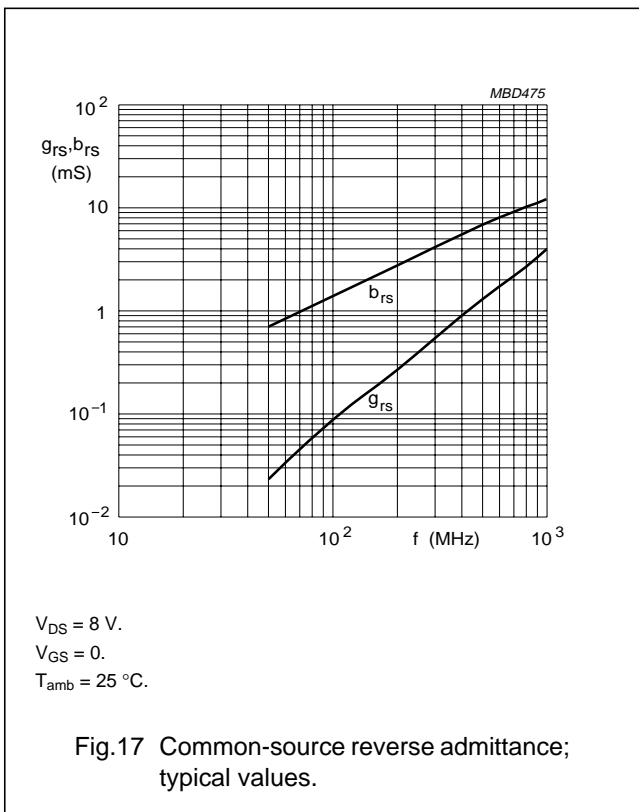
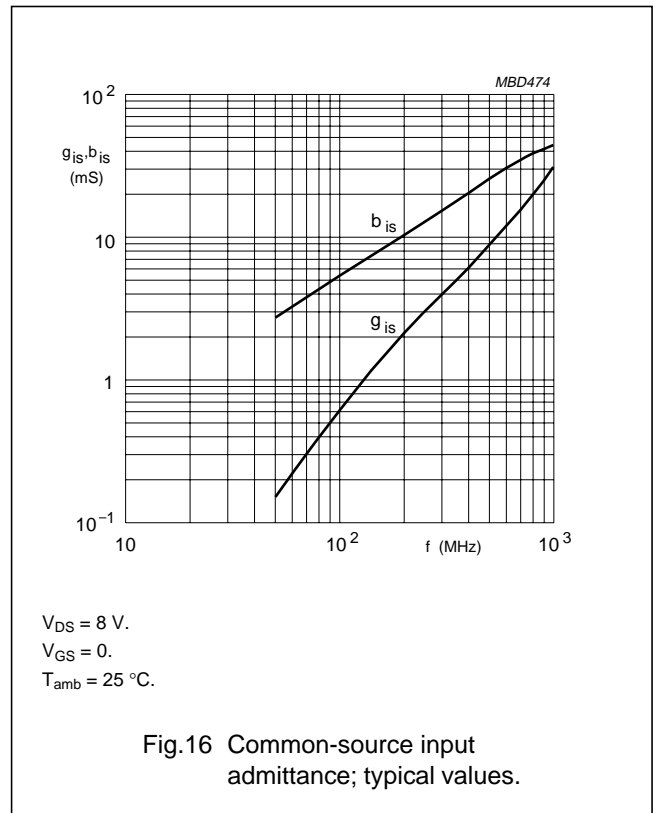
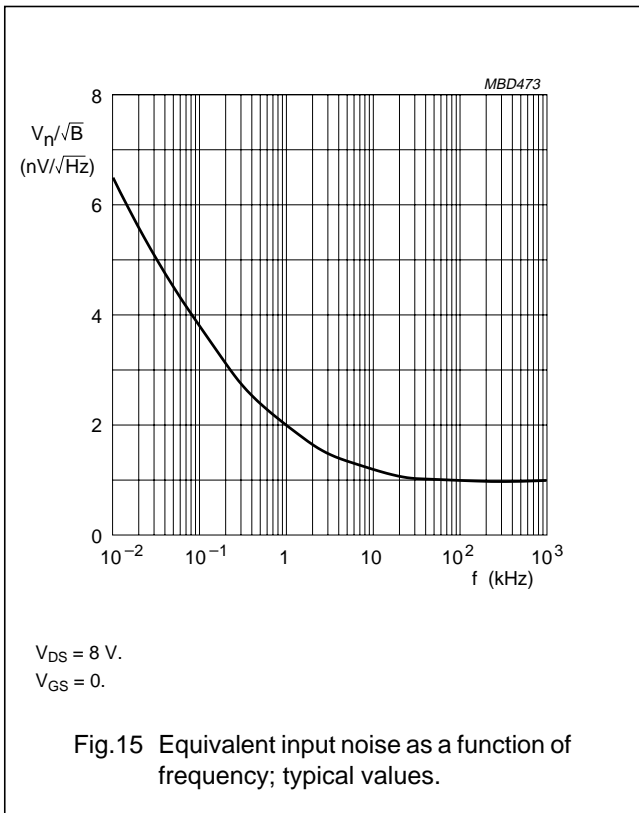
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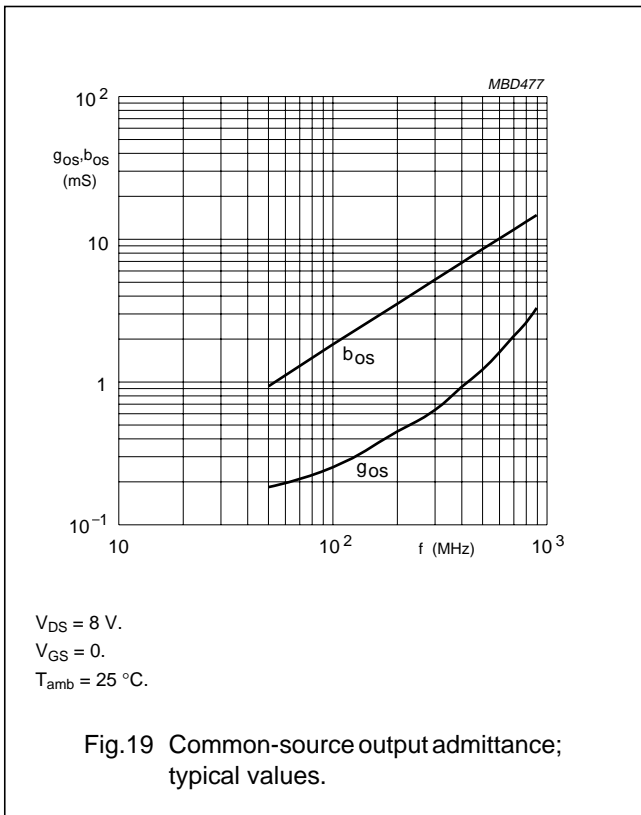
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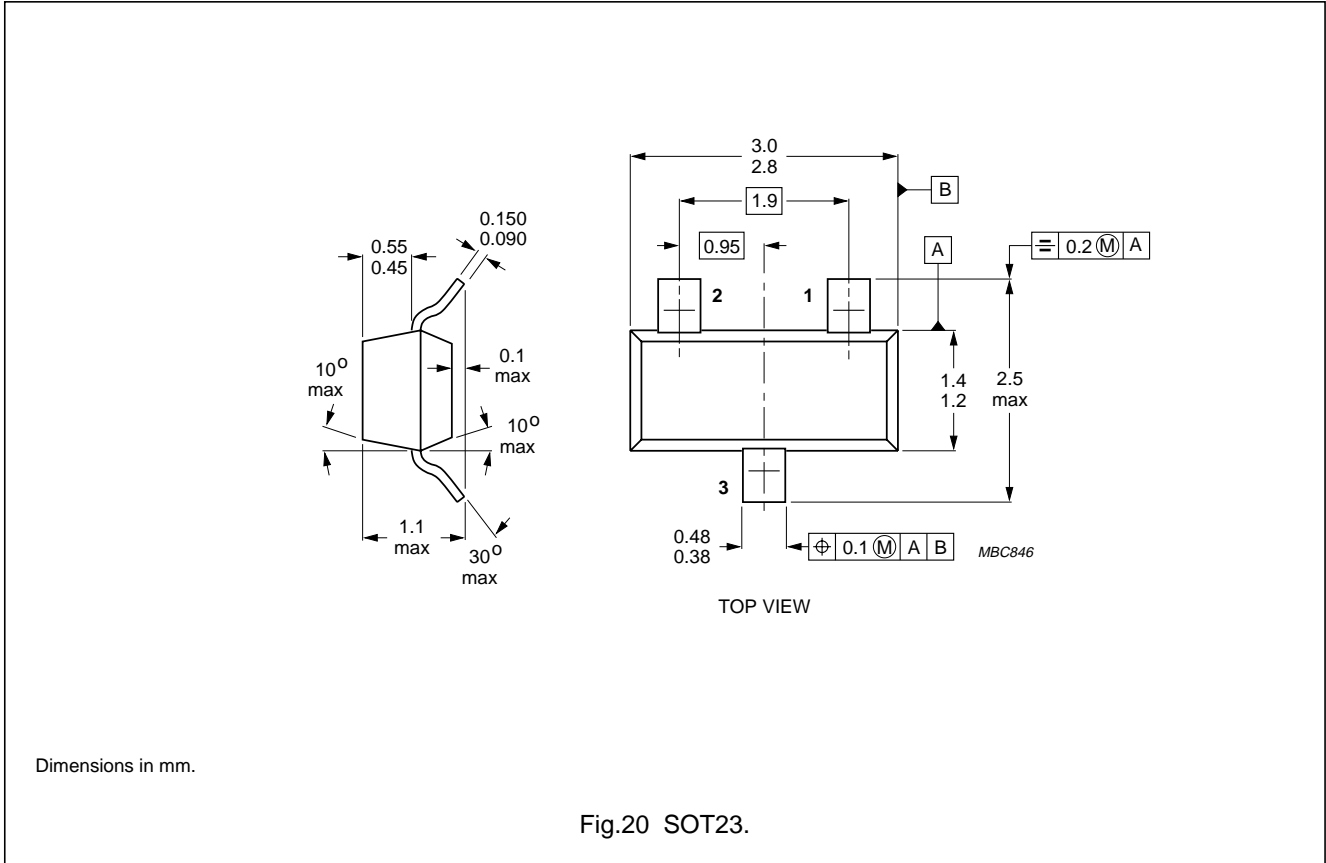
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PACKAGE OUTLINE



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DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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Printed in The Netherlands

117067/00/03/pp12

Date of release: 1997 Sep 04

Document order number: 9397 750 02667

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